

Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	40	V	
Gate-Source Voltage		V _{GS}	±20		
Continuous Drain Current ^(Note 3)	Tc=25°C	- I _D	100		
	$T_{C}=100^{\circ}C$		100	А	
Pulsed Drain Current ^(Note 1)	Tc=25°C	I _{DM}	400		
Power Dissipation	Tc=25°C	D	250	w	
	$T_{C}=100^{\circ}C$	PD	125		
Continuous Drain Current ^(Note 4)	T _A =25 [°] C	l _D	31	Α	
	T _A =70°C		26	A	
Power Dissipation	T _A =25°C	Po	3.8	w	
	T _A =70°C		2.6		
Single Pulse Avalanche Current ^(Note 5)		las	28.5	А	
Single Pulse Avalanche Energy ^(Note 5)		Eas	415	mJ	
Operating Junction and Storage Temperature Range		TJ,TSTG	-55~175	°C	
Thermal Resistance ^(Note 4)	Junction to Case	$R_{ extsf{ heta}JC}$	0.6	°C/W	
	Junction to Ambient	$R_{\theta JA}$	40		



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Electrical Characteristics (TA=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static	· · · · · · · · · · · · · · · · · · ·				·		
Drain-Source Breakdown Voltage	BV _{DSS}	DSS V _{GS} =0V, I _D =250uA		-	-	N	
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =50uA	1.1	1.5	2.3	V	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V, I _D =90A	-	1.72	2.2		
		V _{GS} =4.5V, I _D =50A	-	2.13	2.8	mΩ	
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =40V, V_{GS} =0V	-	-	1	uA	
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V	-	-	±100	nA	
Dynamic ^(Note 6)							
Total Gate Charge	Qg		-	75	100	nC	
Gate-Source Charge	Qgs	V _{DS} =32V, I _D =90A,	-	15	-		
Gate-Drain Charge	Q _{gd}	V _{GS} =10V	-	10	-		
Input Capacitance	Ciss		-	4973	6500	pF	
Output Capacitance	Coss	V _{DS} =25V, V _{GS} =0V, f=1MHz	-	1038	1400		
Reverse Transfer Capacitance	Crss	I=IIVIHZ	-	160	240		
Gate resistance	Rg	f=1MHz	-	1	-	Ω	
Turn-On Delay Time	td _(on)		-	15	-	ns	
Turn-On Rise Time	tr	V _{DS} =32V, I _D =90A,	-	14	-		
Turn-Off Delay Time	td _(off)	$V_{GS}=10V, R_G=3\Omega$	-	71	-		
Turn-Off Fall Time	tf		-	15	-		
Drain-Source Diode							
Diode Forward Current	I _S	T _c =25°C	-	-	100	A	
Pulsed Diode Forward Current	I _{SM}	Tc=25 C	-	-	400		
Diode Forward Voltage	V_{SD}	Is=20A, V _{GS} =0V	-	0.8	1.3	V	
Reverse Recovery Time	Trr	V _{DD} =32V,V _{GS} =0V	-	45	-	ns	
Reverse Recovery Charge	Qrr	Is=20A,dIs/dt=100A/us	-	36	-	nC	

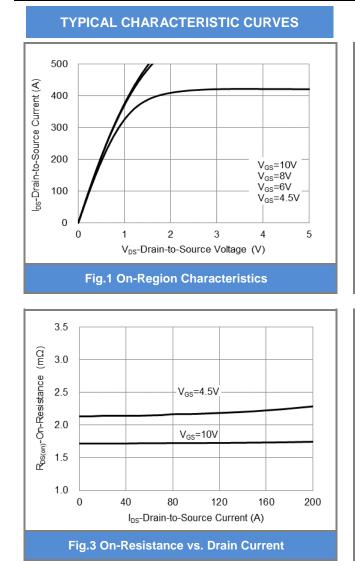
NOTES :

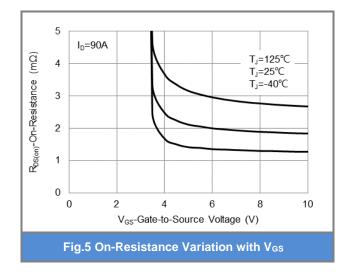
- 1. Pulse width300us, Duty cycle<2%.</td>
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Chip capability with an $R_{\theta JC}=0.6^{\circ}C/W$, Package limited 100A.
- 4. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 5. E_{AS} is calculated based on the condition of L=1mH, I_{AS}=28.8A, V_{DD}=30V, V_{GS}=10V. 100% test at L=0.5mH, I_{AS}=28.5A in production.
- 6. Guaranteed by design, not subject to production testing.

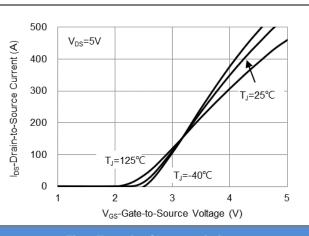
SEMI CONDUCTOR

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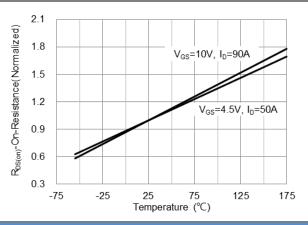
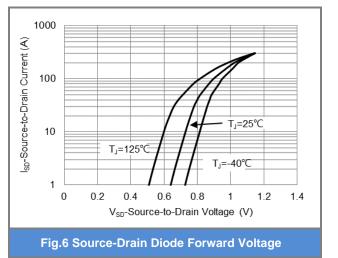


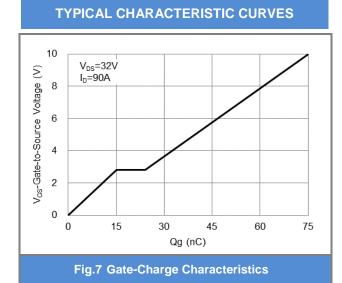
Fig.4 On-Resistance vs. Junction temperature

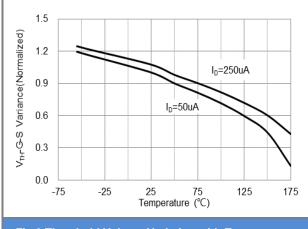


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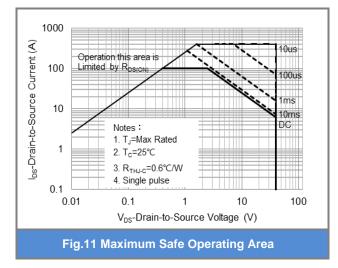
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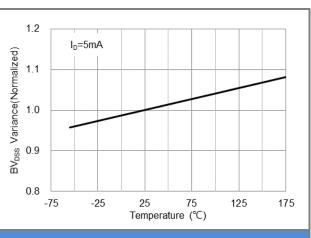
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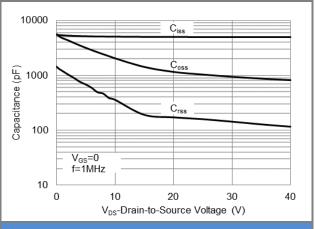
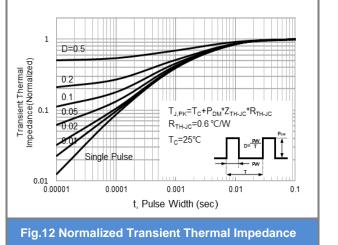


Fig.10 Capacitance vs. Drain-Source Voltage



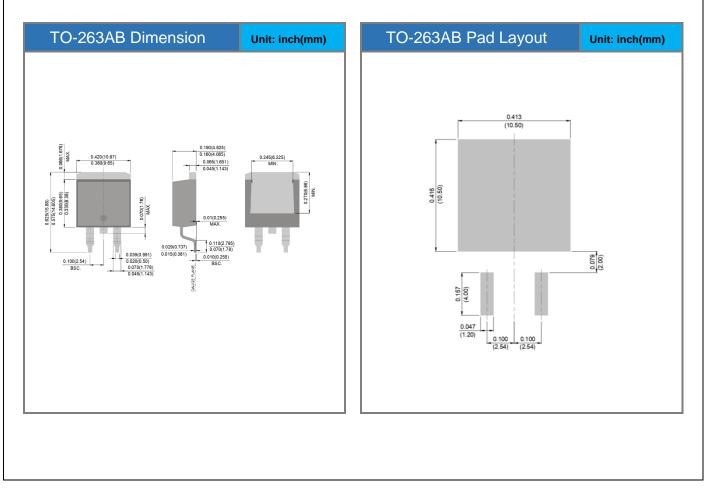


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Product and Packing Information

Part No.	Package Type	Packing Type	Marking	
PJB100N04S-AU	TO-263AB	800 pcs / 13" reel	100N04S	

Packaging Information & Mounting Pad Layout





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